

Effect of Package Trace and Termination Resistance on Tx Specification

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Background

- I have reported that we may need to revise package trace impedance (Z_c , 90Ω) and termination resistance (R_d , 55Ω) in the COM parameters, because they do not necessarily cover corner cases (hidaka_100516_3cd_adhoc.pdf)
- There was a concern that Tx-related COM parameters such as signal amplitude and SNR_{TX} may have to be changed consistently with package parameters, because Tx output amplitude and Tx SNDR will be also affected by the package trace impedance and termination resistance
- Hence, I have studied the effect of package trace impedance and termination resistance on Tx output amplitude and Tx SNDR

Simulated Package Parameters

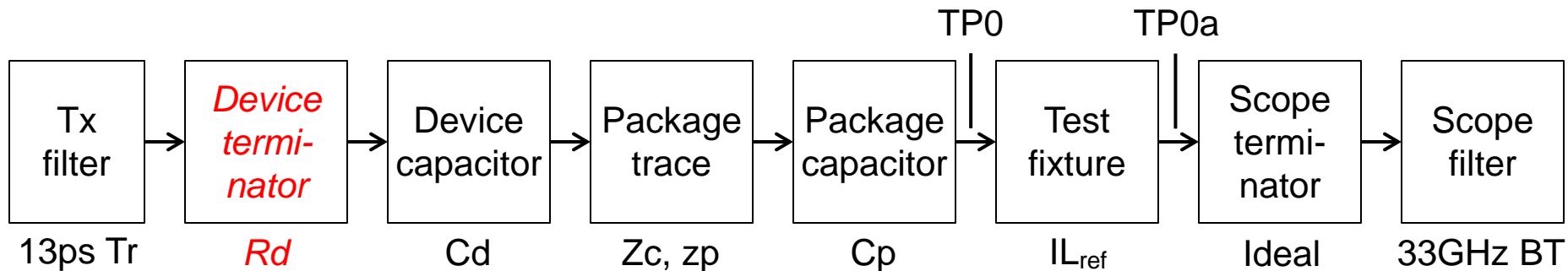
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- The following 10 combinations of parameters were simulated

Case	zp Package trace length	Rd Termination resistance	Zc Package trace impedance
#1	12 mm	45 Ω	90 Ω
#2			110 Ω
#3		55 Ω	90 Ω
#4			110 Ω
#5	30 mm	45 Ω	90 Ω
#6			110 Ω
#7		55 Ω	90 Ω
#8			110 Ω
#9	12 mm	50 Ω	100 Ω
#10	30 mm		

- The original conditions were #3 and #7
- The proposed conditions were #2/#3/#4 and #6/#7/#8
 - See hidaka_100516_3cd_adhoc.pdf

Simulated Model

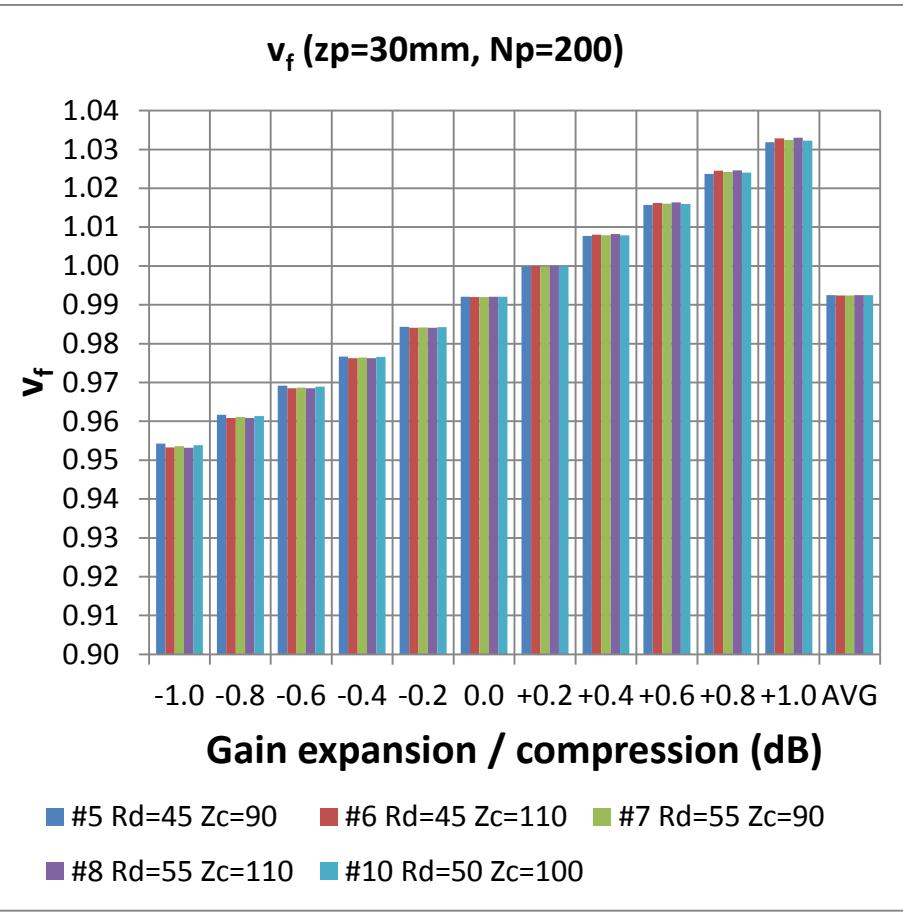
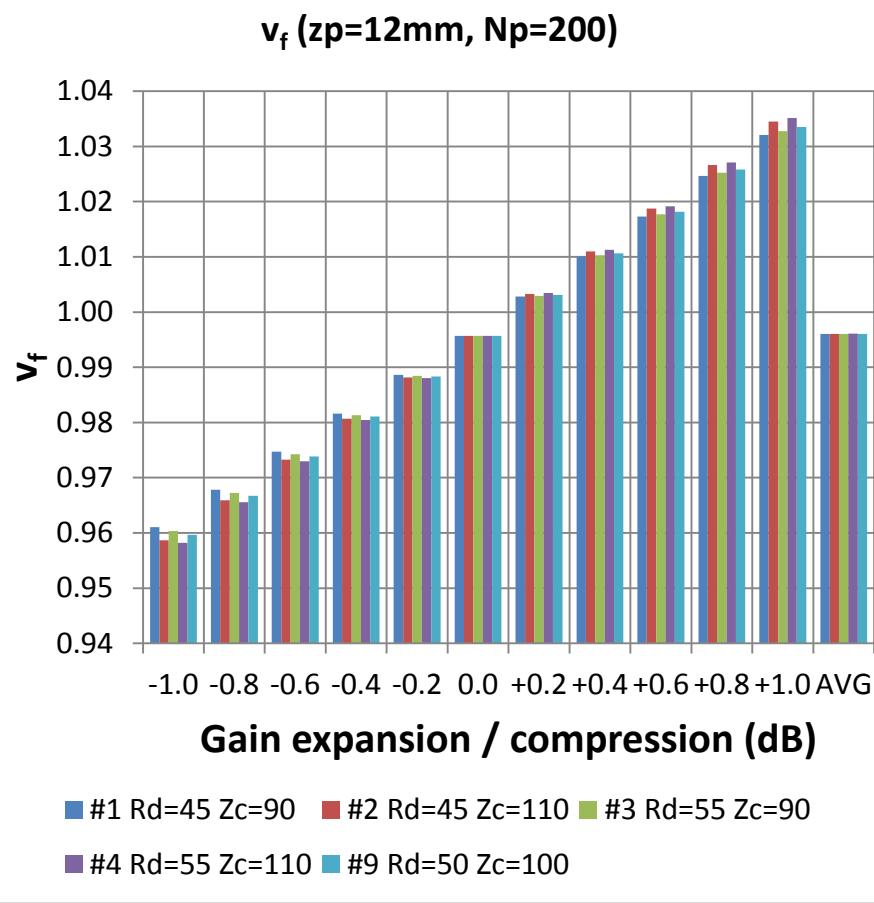


- Tx filter: $S_{21} = (\text{EQ93A-46} | T_r = 13\text{ps}, \beta = 2)$ (i.e. 13ps 20-80% Tr)
- Device terminator: $S_{21} = 1, S_{22} = \frac{R_d - 50\Omega}{R_d + 50\Omega}$ (i.e. same as Tx in COM)
 - No effect of impedance matching on amplitude (i.e. only effect on reflection)
- Device capacitor: $S = (\text{EQ93A-8} | C = C_d)$
- Package trace: $S = (\text{EQ93A-13,14} | \text{Table93A-3 except } Z_c, z_p)$
- Package capacitor: $S = (\text{EQ93A-8} | C = C_p)$
- Test fixture: $|S_{21}| = 10^{-(\text{EQ93-1})/20}, \angle S_{21} = \text{minimum phase}(|S_{21}|)$
- Scope terminator: $S_{21} = 1, S_{11} = 0$ (i.e. ideal)
- Scope filter: 4-th order Bessel-Thomson LPF with 33GHz 3dB BW
 - $\omega_0 = 98.28967142447435 \text{ G rad/s}$

Effect on v_f ($N_p=200$)

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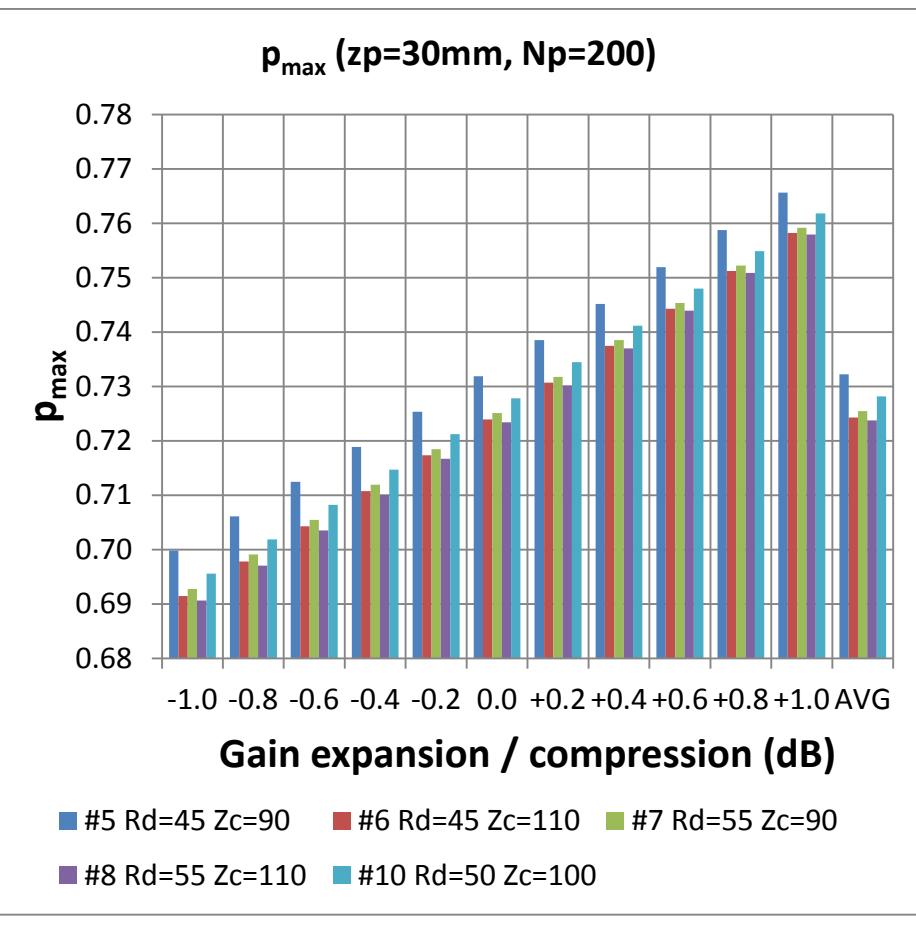
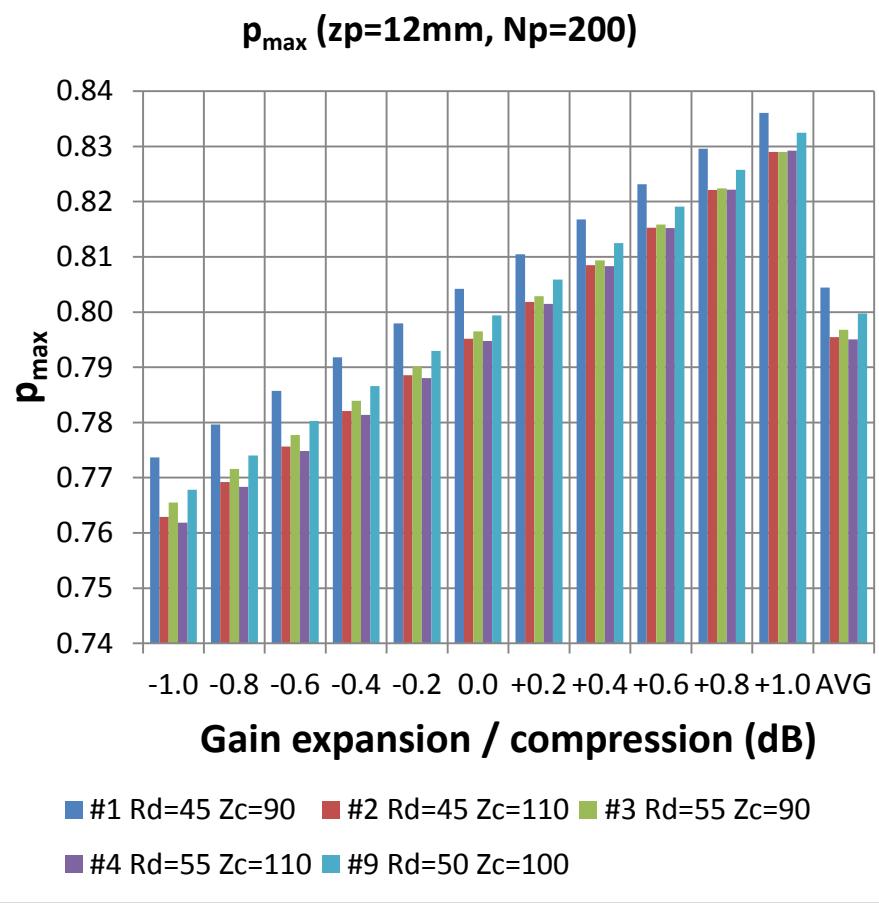
- The effect of R_d and Z_c on v_f is very small



Effect on p_{\max} ($N_p=200$)

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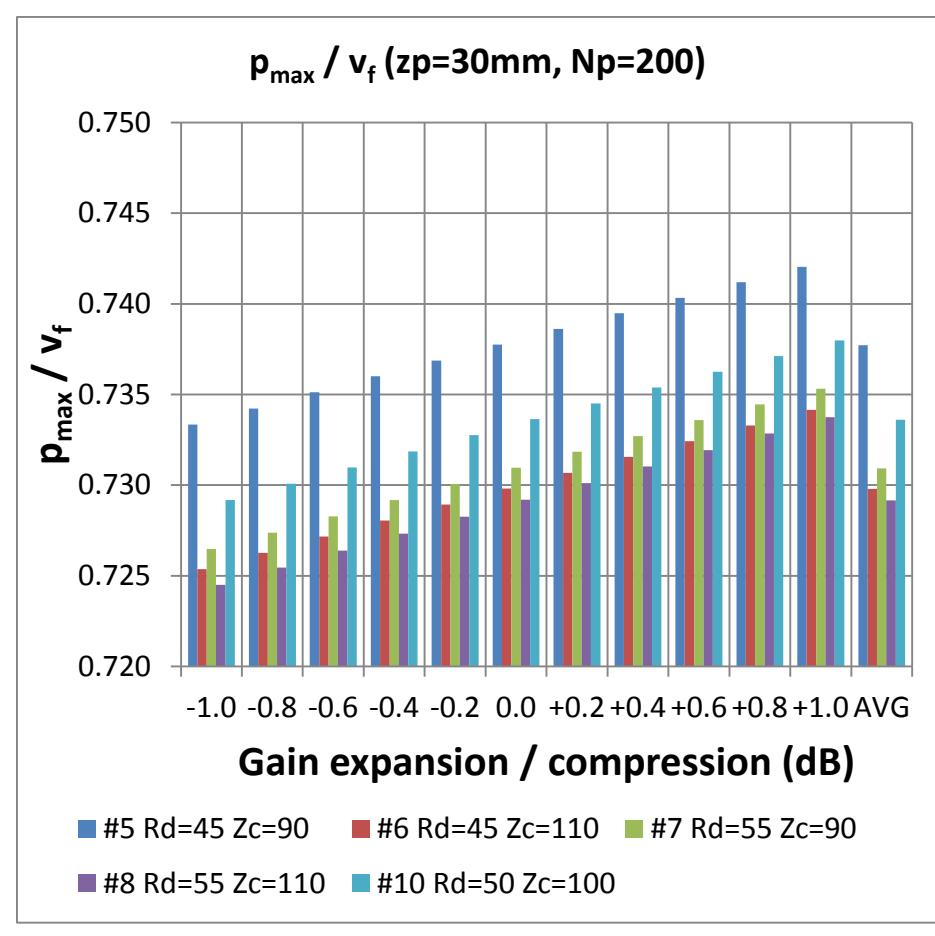
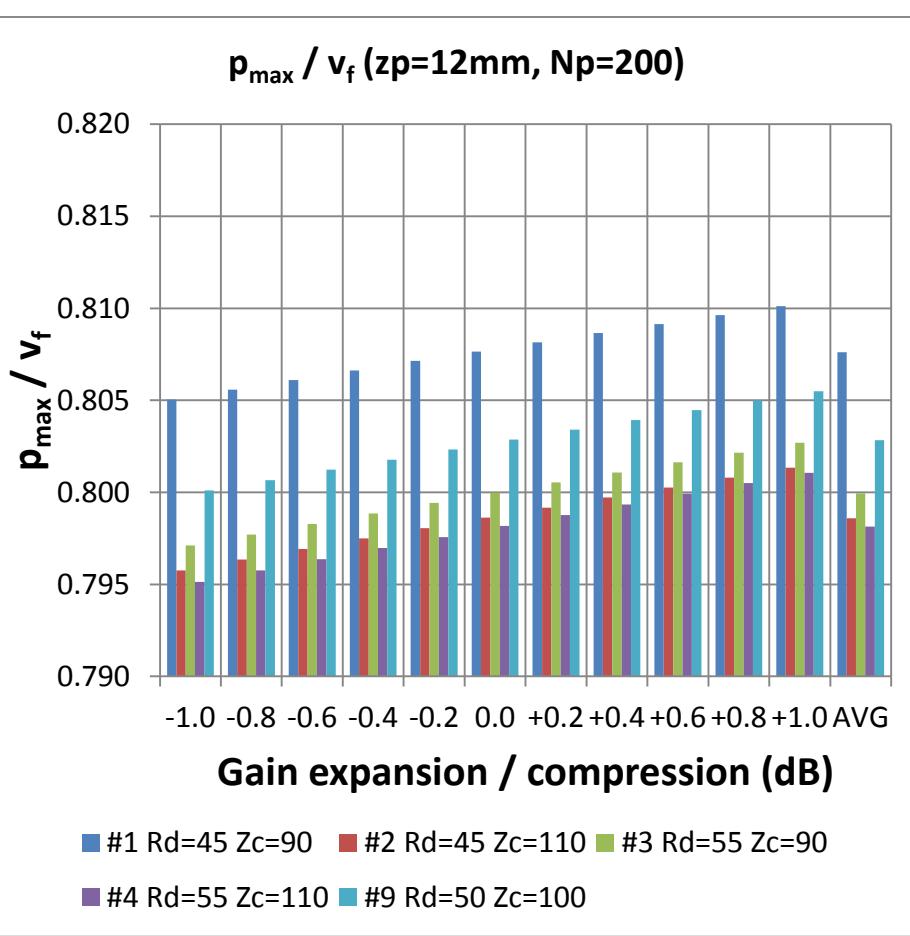
- The effect of R_d and Z_c on p_{\max} is very small



Effect on the Ratio of p_{\max} to v_f ($N_p=200$)

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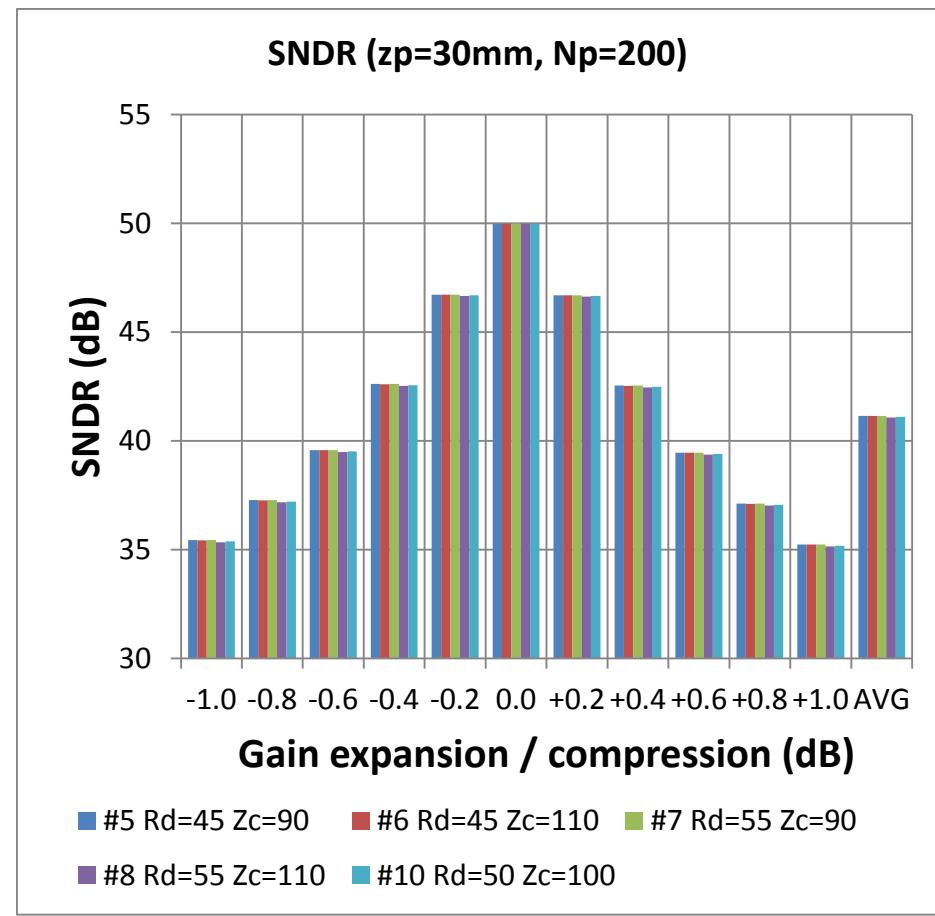
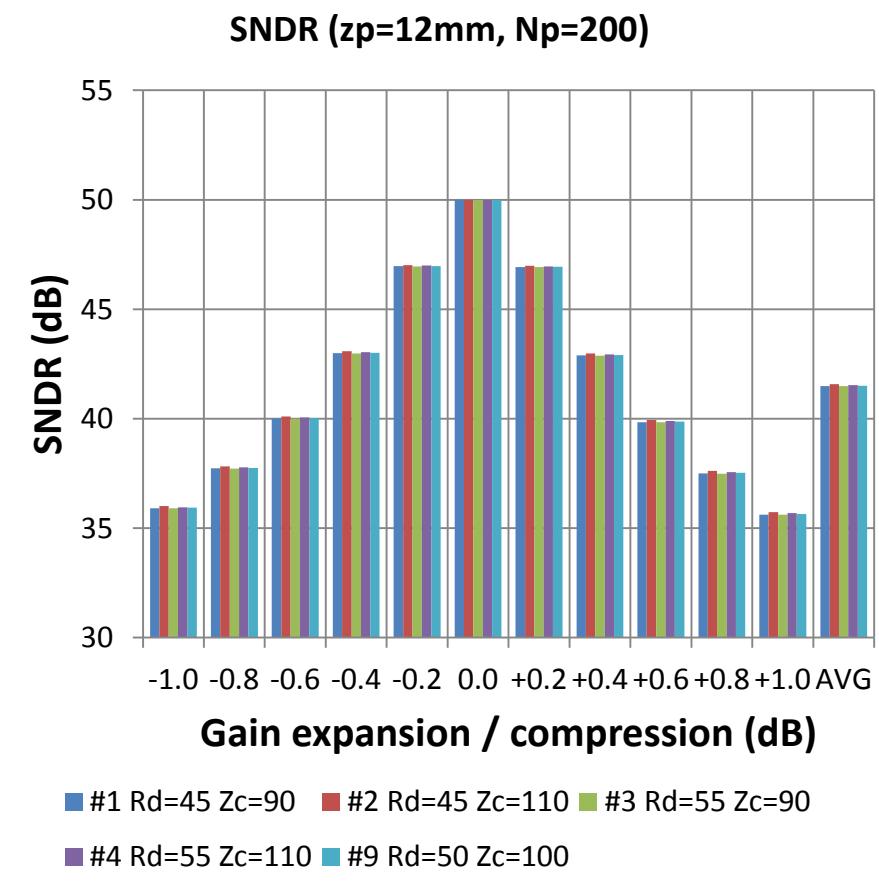
- The effect of R_d and Z_c on the ratio of p_{\max} to v_f is rather small between proposed conditions (#2/3/4, #6/7/8)



Effect on SNDR (Np=200)

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- The effect of Rd and Zc on SNDR is very small



Conclusion

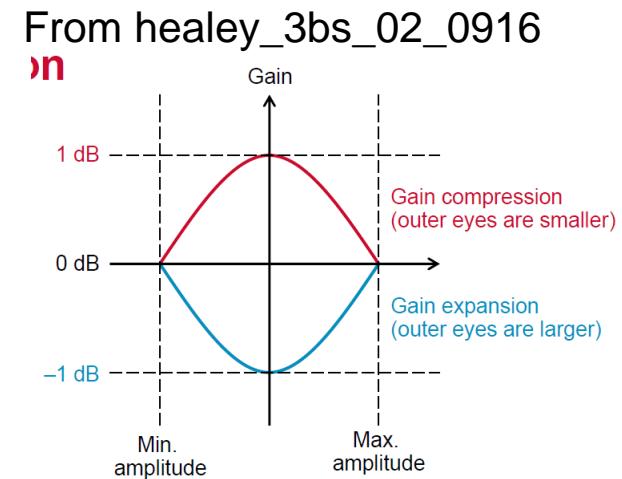
- The effects on the p_{\max} -to- v_f ratio and the SNDR are rather small

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■ Simulation Methodology

Simulation Methodology

1. Get S_{21} of the entire model from 1MHz to f_{max} with 1MHz step
 - $f_{max} = 26.5625\text{GHz} \times M \div 2$, where $M = 32$
2. Get a single-bit pulse response
3. Get a linear cycle response of PRBS13Q with ideal levels
4. Cancel the DC offset of the linear cycle response of PRBS13Q
5. Get a non-linear cycle response of PRBS13Q by gain expansion / compression (similar to a methodology in healey_3bs_02_0916)
 - Simulated from -1.0dB to +1.0dB with 0.2dB step
6. Get V0, V1, V2, and V3 per 120D.3.1.2.1
7. Get Vmid, ES1, and ES2 per 120D.3.1.2
8. Get $ES = (ES1 + ES2) / 2$ per 120D.3.1.3
9. Get linear fit pulse $p(k)$ and error $e(k)$ per 120D.3.1.3, 94.3.12.5.2, 85.8.3.3.5
 - $Dp=2$ and $Np=200$
10. Get steady-state voltage v_f and linear fit pulse peak p_{max} per 120D.3.1.4
11. Get σ_e from $e(k)$, then get SNDR per 120D.3.1.6
 - σ_n is always set to $p_{max} \times 10^{(-50/20)}$ (i.e. -50dB) to have noise floor



Thank you